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**PATENT APPLICATION**

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Masahiro SAKURADA et al.

Group Art Unit: 1722

Application No.: 10/538,878

Examiner: F. HITESHEW

Filed: June 14, 2005

Docket No.: 124231

For: METHOD OF PRODUCING P-DOPED SILICON SINGLE CRYSTAL AND P-DOPED  
N-TYPE SILICON SINGLE CRYSTAL WAFER

**AMENDMENT UNDER 37 C.F.R. §1.111**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

In reply to the June 15, 2006, Office Action, please consider the following:

**Amendments to the Claims** as reflected in the listing of claims; and

**Remarks.**